

APPLICATIONS

V_{GE}	Gate Emitter Voltage		± 20	
I_C	DC Collector Current	$T_C=25$	65	A
		$T_C=110$	40	
I_{Cpuls}	Pulsed collector current, tp limited by T_{Jmax}		130	
P_{tot}	Power Dissipation Per IGBT		454	
V_{RRM}	Repetitive Reverse Voltage	$T_J=25$	1200	
$I_{F(AV)}$				

MM40GTU120B

$I_c(A)$

$I_c(A)$

$V_{CE} \text{ \AA } V \text{ \AA}$

V_{CE}

Dimensions in (mm)
Figure 13. Package Outline